

五、著作目錄(建議呈現與計畫相關之著作目錄，頁數以2頁為限)：

- 1 *Ya-Hsiang Tai**, Chi-Hao Lin, and Wei-Jia Cheu, "Active In-Cell Touch Circuit using Floating Common Electrode as Sensing Pad for the Large Size In-Plane-Switching Liquid Crystal Displays," Journal of the Society for Information Display, Accepted, 2017.
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- 12 Yi-Jung Chen* and *Ya-Hsiang Tai*, "Hysteresis of Transistor Characteristics of Amorphous IGZO TFTs Studied by Controlling Measurement Speed," ECS SOLID-STATE LETTERS, VOL. 4 No. 4, PP. Q10-Q12, 2015.
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